# BLS7G2730L-200P; BLS7G2730LS-200P LDMOS S-band radar power transistor

**AMPLEON** 

Rev. 4 — 1 September 2015

Product data sheet

### **Product profile**

### 1.1 General description

200 W LDMOS power transistor for S-band radar applications in the frequency range from 2700 MHz to 3000 MHz.

**Typical performance** Table 1.

Typical RF performance at  $T_{case} = 25$  °C.

Test signal	f	V <sub>DS</sub>	PL	Gp	η <sub>D</sub>	t <sub>r</sub>	t <sub>f</sub>
	(GHz)	(V)	(W)	(dB)	(%)	(ns)	(ns)
Class-AB production test circuit							
pulsed RF [1]	2.7 to 3.0	32	200	12	48	8	5
Application circuit							
pulsed RF [2]	2.7 to 3.0	32	220	12.5	50	20	6
pulsed RF [3]	2.9 to 3.1	32	220	12.5	50	20	6

<sup>[1]</sup>  $t_p = 300 \ \mu s$ ;  $\delta = 10 \ \%$ ;  $I_{Dq} = 100 \ mA$ 

### 1.2 Features and benefits

- High efficiency
- Excellent ruggedness
- Designed for broadband operation
- Excellent thermal stability
- Easy power control
- Integrated ESD protection
- High flexibility with respect to pulse formats
- Internally matched for ease of use
- Compliant to Directive 2002/95/EC, regarding Restriction of Hazardous Substances (RoHS)

### 1.3 Applications

S-band radar applications in the frequency range 2700 MHz to 3000 MHz

<sup>[2]</sup>  $t_p = 3000 \,\mu s$ ;  $\delta = 20 \,\%$ ;  $I_{Dq} = 50 \,mA$ 

<sup>[3]</sup>  $t_p = 500 \,\mu\text{s}; \, \delta = 20 \,\%; \, I_{Dq} = 50 \,\text{mA}$ 

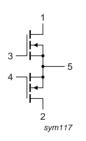
# **Pinning information**

Table 2. **Pinning** 

Pin	Description	Simplified outline	Graphic symbol
BLS7G273	30L-200P (SOT539A)		
1	drain1	, ,	,
2	drain2	1 2	<u>1</u> ا
3	gate1	5	3
4	gate2	3 4	5
5	source	<u>[1]</u>	4
			2
			sym117

BLS7G2	730LS-200P (SOT539B)	
1	drain1	
2	drain2	
3	gate1	
4	gate2	
5	source	<u>[1]</u>





# **Ordering information**

Table 3. **Ordering information** 

Type number	Package			
	Name	Description	Version	
BLS7G2730L-200P	-	flanged balanced ceramic package; 2 mounting holes; 4 leads	SOT539A	
BLS7G2730LS-200P	-	earless flanged balanced ceramic package; 4 leads	SOT539B	

# **Limiting values**

**Limiting values** 

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Min	Max	Unit
$V_{DS}$	drain-source voltage	-	65	V
$V_{GS}$	gate-source voltage	-0.5	+13	V
T <sub>stg</sub>	storage temperature	-65	+150	°C
Tj	junction temperature	<u>[1]</u> _	225	°C

<sup>[1]</sup> Continuous use at maximum temperature will affect the reliability.

<sup>[1]</sup> Connected to flange.

### 5. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Тур	Unit
$Z_{\text{th(j-c)}}$	transient thermal impedance from junction	$T_{case}$ = 85 °C; $P_L$ = 200 W		
	to case	$t_p$ = 300 $\mu$ s; $\delta$ = 10 %	0.13	K/W
		$t_p$ = 3000 $\mu$ s; $\delta$ = 20 %	0.19	K/W

### 6. Characteristics

Table 6. DC characteristics

 $T_i = 25$  °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{(BR)DSS}$	drain-source breakdown voltage	$V_{GS} = 0 \text{ V}; I_D = 1.2 \text{ mA}$	65	-	-	V
$V_{GS(th)}$	gate-source threshold voltage	$V_{DS}$ = 10 V; $I_{D}$ = 120 mA	1.5	1.9	2.3	V
I <sub>DSS</sub>	drain leakage current	$V_{GS} = 0 \text{ V}; V_{DS} = 28 \text{ V}$	-	-	2.8	μΑ
I <sub>DSX</sub>	drain cut-off current	$V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $V_{DS} = 10 \text{ V}$	-	22.5	-	Α
$I_{GSS}$	gate leakage current	$V_{GS}$ = 11 V; $V_{DS}$ = 0 V	-	-	280	nΑ
g <sub>fs</sub>	forward transconductance	$V_{DS}$ = 10 V; $I_{D}$ = 0.12 A	-	1	-	S
R <sub>DS(on)</sub>	drain-source on-state resistance	$V_{GS} = V_{GS(th)} + 3.75 V;$ $I_D = 4.2 A$	-	0.13	-	Ω

Table 7. RF characteristics

Test signal: pulsed RF;  $t_p = 300 \ \mu s$ ;  $\delta = 10 \ \%$ ; RF performance at  $V_{DS} = 32 \ V$ ;  $I_{Dq} = 100 \ mA$ ;  $T_{case} = 25 \ ^{\circ}C$ ; unless otherwise specified, in a class-AB production test circuit.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Gp	power gain	P <sub>L</sub> = 200 W	9.8	12	-	dB
RLin	input return loss	P <sub>L</sub> = 200 W	-	-10	-6	dB
η <sub>D</sub>	drain efficiency	P <sub>L</sub> = 200 W	43	48	-	%
P <sub>droop(pulse)</sub>	pulse droop power	P <sub>L</sub> = 200 W	-	0	0.25	dB
t <sub>r</sub>	rise time	P <sub>L</sub> = 200 W	-	8	50	ns
t <sub>f</sub>	fall time	P <sub>L</sub> = 200 W	-	5	50	ns

### 7. Test information

### 7.1 Ruggedness in class-AB operation

The BLS7G2730L-200P and BLS7G2730LS-200P are capable of withstanding a load mismatch corresponding to VSWR = 10 : 1 through all phases under following conditions:  $V_{DS}$  = 32 V;  $I_{Dq}$  = 100 mA;  $P_L$  = 200 W; f = 2700 MHz;  $t_p$  = 300  $\mu$ s;  $\delta$  = 10 %

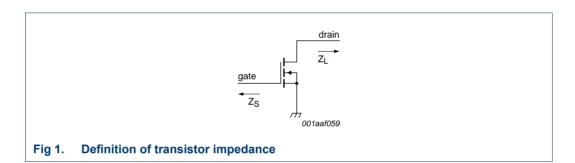
### 7.2 Impedance information

Table 8. Typical impedance

Measured load-pull data half device;  $V_{DS} = 32 \text{ V}$ ;  $I_{Dq} = 100 \text{ mA}$ .

	•	
f	Z <sub>S</sub> [1]	Z <sub>L</sub> [1]
(MHz)	(Ω)	(Ω)
2700	2.0 – j5.8	3.7 – j6.4
2800	1.6 – j5.9	3.8 – j6.9
2900	2.6 – j6.2	3.8 – j6.9
3000	3.4 – j6.0	3.7 – j6.4

[1] Z<sub>S</sub> and Z<sub>L</sub> defined in Figure 1.



### 7.3 Production test circuit

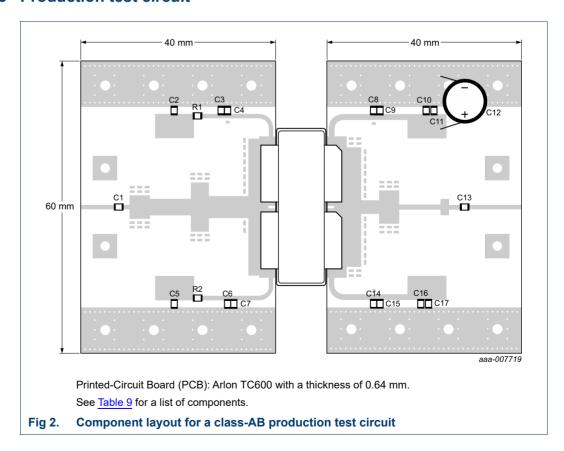


Table 9. List of components test circuit See Figure 2.

Component	Description	Value	Remarks
C1, C3, C6, C9, C13, C15	multilayer ceramic chip capacitor	18 pF	11 ATC600F
C2, C5, C10, C16	multilayer ceramic chip capacitor	1 μF	[2]
C4, C7, C8, C14	multilayer ceramic chip capacitor	12 pF	11 ATC600F
C11, C17	multilayer ceramic chip capacitor	10 μF	[2]
C12	electrolytic capacitor	2200 μF, 63 V	
R1, R2	chip resistor	9.1 Ω	[3]

- [1] American Technical Ceramics type 600F or capacitor of same quality.
- [2] Murata or capacitor of same quality.
- [3] Vishay Dale or capacitor of same quality.

### 7.4 Application circuit

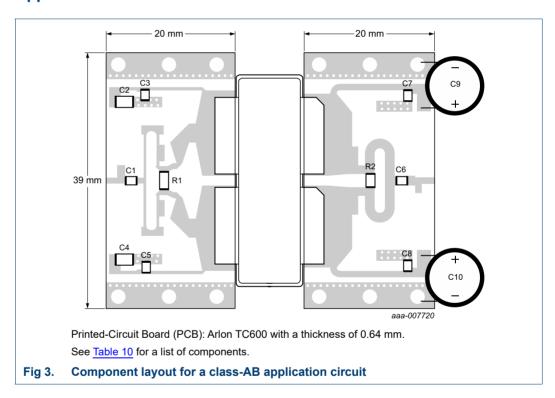


Table 10. List of components application circuit See *Figure 2*.

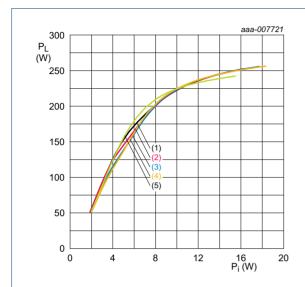
Component	Description	Value	Remarks
C1, C3, C5, C6, C7, C8	multilayer ceramic chip capacitor	12 pF	11 ATC600F
C2, C4	multilayer ceramic chip capacitor	1 μF	[2]
C9, C10	electrolytic capacitor	2200 μF, 50 V	
R1, R2	chip resistor	50 Ω	[3]

- [1] American Technical Ceramics type 600F or capacitor of same quality.
- [2] Murata or capacitor of same quality.
- [3] Vishay Dale or capacitor of same quality.

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### 7.5 Graphical data

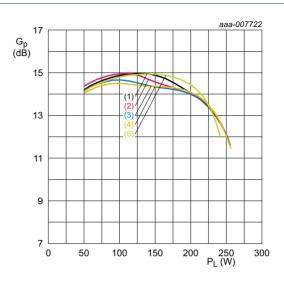
### 7.5.1 Test circuit



 $V_{DS}$  = 32 V;  $I_{Dq}$  = 100 mA;  $t_p$  = 300  $\mu$ s;  $\delta$  = 10 %.

- (1) f = 2700 MHz
- (2) f = 2800 MHz
- (3) f = 2850 MHz
- (4) f = 2900 MHz
- (5) f = 3000 MHz

Fig 4. Output power as a function of input power; typical values



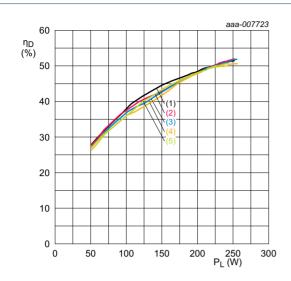
 $V_{DS}$  = 32 V;  $I_{Dq}$  = 100 mA;  $t_p$  = 300  $\mu s; \, \delta$  = 10 %.

- (1) f = 2700 MHz
- (2) f = 2800 MHz
- (3) f = 2850 MHz
- (4) f = 2900 MHz
- (5) f = 3000 MHz

Fig 5. Power gain as a function of output power; typical values

# BLS7G2730L(S)-200P

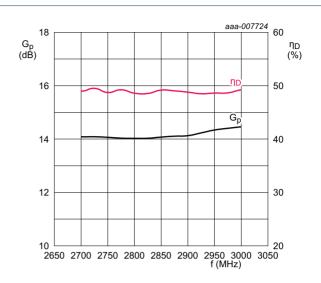
### LDMOS S-band radar power transistor



 $V_{DS}$  = 32 V;  $I_{Dq}$  = 100 mA;  $t_p$  = 300  $\mu$ s;  $\delta$  = 10 %.

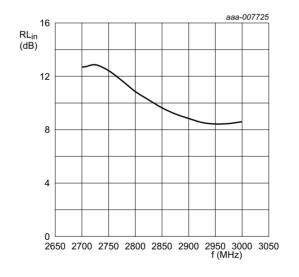
- (1) f = 2700 MHz
- (2) f = 2800 MHz
- (3) f = 2850 MHz
- (4) f = 2900 MHz
- (5) f = 3000 MHz





 $V_{DS}$  = 32 V;  $P_L$  = 200 W;  $I_{Dq}$  = 100 mA;  $t_p$  = 300  $\mu s;$   $\delta$  = 10 %.

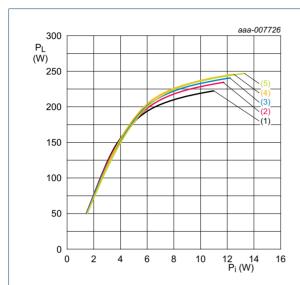
# Fig 7. Power gain and drain efficiency as function of frequency; typical values



 $V_{DS}$  = 32 V;  $P_L$  = 200 W;  $I_{Dq}$  = 100 mA;  $t_p$  = 300  $\mu s;$   $\delta$  = 10 %.

Fig 8. Input return loss as a function of frequency; typical values

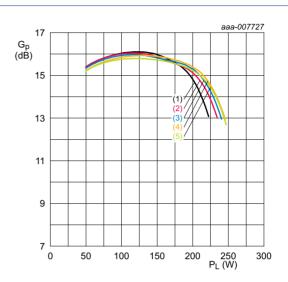
### 7.5.2 Application circuit



 $V_{DS}$  = 32 V;  $I_{Dq}$  = 50 mA;  $t_p$  = 3000  $\mu$ s;  $\delta$  = 20 %.

- (1) f = 2700 MHz
- (2) f = 2800 MHz
- (3) f = 2850 MHz
- (4) f = 2900 MHz
- (5) f = 3000 MHz

Fig 9. Output power as a function of input power; typical values



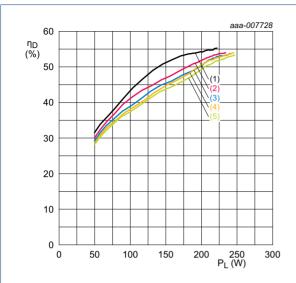
 $V_{DS}$  = 32 V;  $I_{Dq}$  = 50 mA;  $t_p$  = 3000  $\mu$ s;  $\delta$  = 20 %.

- (1) f = 2700 MHz
- (2) f = 2800 MHz
- (3) f = 2850 MHz
- (4) f = 2900 MHz
- (5) f = 3000 MHz

Fig 10. Power gain as a function of output power; typical values

# BLS7G2730L(S)-200P

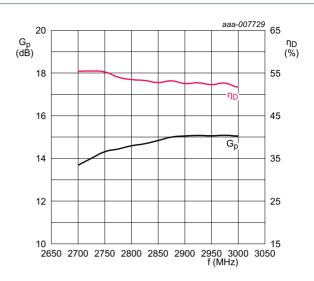
### **LDMOS S-band radar power transistor**



 $V_{DS}$  = 32 V;  $I_{Dq}$  = 50 mA;  $t_p$  = 3000  $\mu s;$   $\delta$  = 20 %.

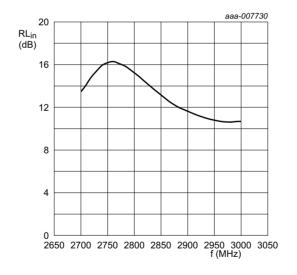
- (1) f = 2700 MHz
- (2) f = 2800 MHz
- (3) f = 2850 MHz
- (4) f = 2900 MHz
- (5) f = 3000 MHz

Fig 11. Drain efficiency as a function of output power; typical values



 $V_{DS}$  = 32 V;  $P_L$  = 220 W;  $I_{Dq}$  = 50 mA;  $t_p$  = 3000  $\mu s;$   $\delta$  = 20 %.

Fig 12. Power gain and drain efficiency as function of frequency; typical values



 $V_{DS}$  = 32 V;  $P_L$  = 220 W;  $I_{Dq}$  = 50 mA;  $t_p$  = 3000  $\mu s; \, \delta$  = 20 %.

Fig 13. Input return loss as a function of frequency; typical values

## 8. Package outline

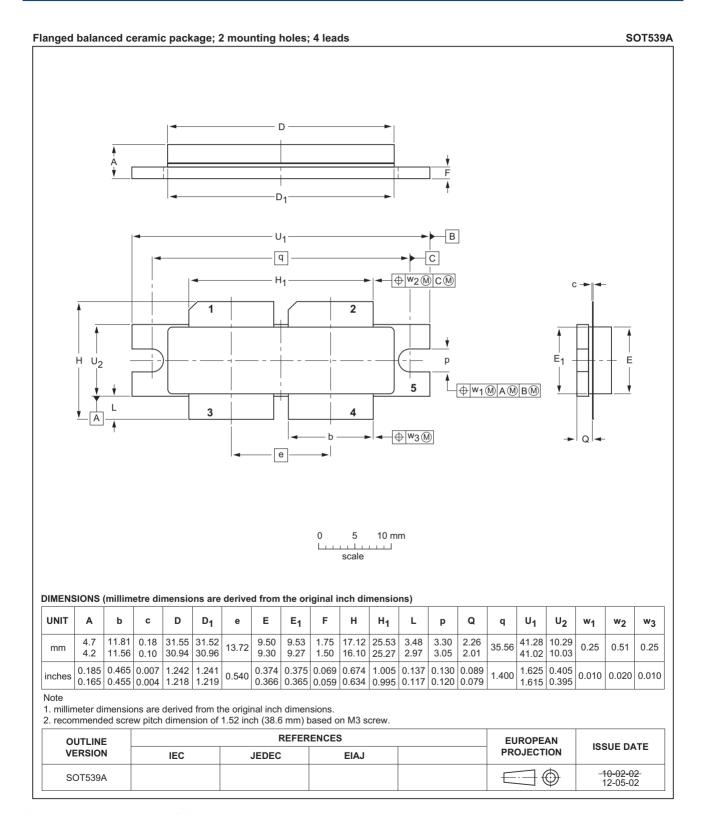


Fig 14. Package outline SOT539A

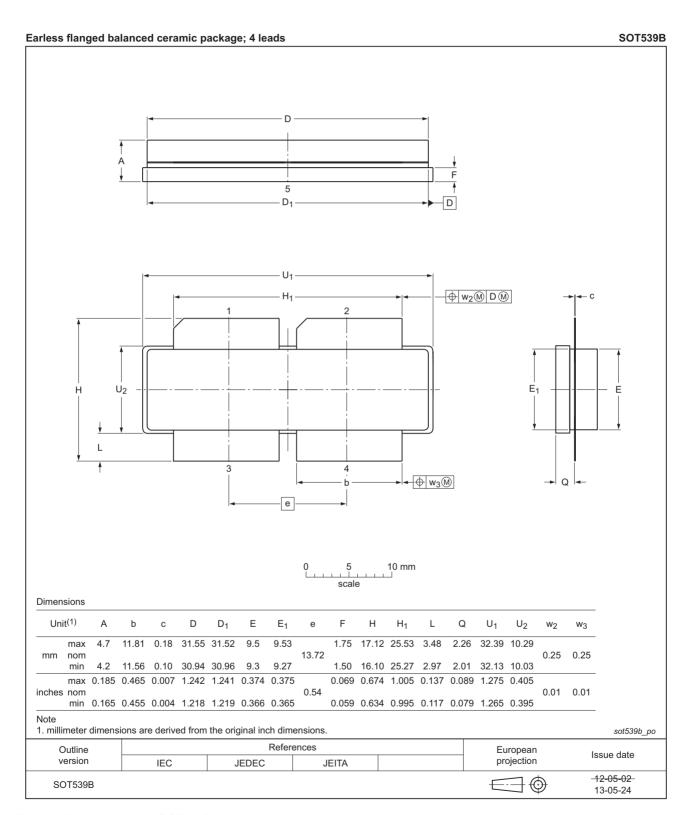


Fig 15. Package outline SOT539B

# 9. Handling information

### CAUTION



This device is sensitive to ElectroStatic Discharge (ESD). Observe precautions for handling electrostatic sensitive devices.

Such precautions are described in the ANSI/ESD S20.20, IEC/ST 61340-5, JESD625-A or equivalent standards.

### 10. Abbreviations

Table 11. Abbreviations

Acronym	Description
ESD	ElectroStatic Discharge
LDMOS	Laterally Diffused Metal-Oxide Semiconductor
S-band	Short wave band
VSWR	Voltage Standing-Wave Ratio

# 11. Revision history

Table 12. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes			
BLS7G2730S-200P_LS-200P#4	20150901	Product data sheet		BLS7G2730S-200P_LS-200P v.3			
Modifications:	<ul> <li>The format of this document has been redesigned to comply with the new identity guidelines of Ampleon.</li> <li>Legal texts have been adapted to the new company name where appropriate.</li> </ul>						
BLS7G2730S-200P_LS-200P v.3	20130712	Product data sheet	-	BLS7G2730S-200P_LS-200P v.2			
BLS7G2730S-200P_LS-200P v.2	20130603	Product data sheet	-	BLS7G2730S-200P_LS-200P v.1			
BLS7G2730S-200P_LS-200P v.1	20130129	Objective data sheet	-	-			

### 12. Legal information

### 12.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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# BLS7G2730L(S)-200P

#### LDMOS S-band radar power transistor

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# **AMPLEON**

# BLS7G2730L(S)-200P

**LDMOS S-band radar power transistor** 

### 14. Contents

1	Product profile	1
1.1	General description	1
1.2	Features and benefits	1
1.3	Applications	1
2	Pinning information	2
3	Ordering information	2
4	Limiting values	2
5	Thermal characteristics	3
6	Characteristics	3
7	Test information	3
7.1	Ruggedness in class-AB operation	3
7.2	Impedance information	
7.3	Production test circuit	
7.4	Application circuit	5
7.5	Graphical data	6
7.5.1	Test circuit	
7.5.2	Application circuit	8
8	Package outline	10
9	Handling information	12
10	<del>-</del>	12
11	Revision history	12
12		13
12.1		13
12.2	Definitions	13
12.3	Disclaimers	13
12.4	Trademarks	14
13	Contact information	14
14	Contents	15

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